Diffusive spin-orbit torque at a surface of topological insulator

R. J. Sokolewicz,¹ I. A. Ado,¹ M. I. Katsnelson,^{1,2} P. M. Ostrovsky,^{3,4} and M. Titov^{1,5}

 1 Radboud University, Institute for Molecules and Materials, NL-6525 AJ Nijmegen, the Netherlands

²Theoretical Physics and Applied Mathematics Department,

Ural Federal University, Mira Str. 19, 620002 Ekaterinburg, Russia

³Max Planck Institute for Solid State Research, Heisenbergstr. 1, 70569 Stuttgart, Germany

⁴L. D. Landau Institute for Theoretical Physics RAS, 119334 Moscow, Russia

5 ITMO University, Saint Petersburg 197101, Russia

We investigate spin-orbit torque on magnetization in an insulating ferromagnetic (FM) layer that is brought into a good proximity to a topological insulator (TI). We show that, in addition to the well-known field-like spin-orbit torque that favors in-plane magnetization, there exists also a diffusive spin-orbit torque that favors perpendicular-to-the-plane magnetization. Such a diffusive torque is shown to emerge in the presence of a spatially inhomogeneous low-frequency ac electric field at the TI surface. The required electric field configuration can be created e. g. by a grated top gate, thus, paving way to electric-field control over magnetization direction in FM/TI films.

It is widely known that spin-orbit interaction provides an efficient way to couple electronic and magnetic degrees of freedom. It is, therefore, no wonder that the largest torque on magnetization, which is also referred to as the spin-orbit torque, emerges in magnetic systems with strong spin-orbit interaction $[1, 2]$ $[1, 2]$ $[1, 2]$ as has been long anticipated [\[3\]](#page-3-2).

The spin-orbit coupling may be enhanced by confinement potentials in effectively two-dimensional systems consisting of conducting and magnetic layers. The inplane current may efficiently drive domain walls or switch magnetic orientation in such structures with the help of spin-orbit torque $[4-7]$ $[4-7]$, which is present even for uniform magnetization, or with the help of spin-transfer torque, which requires the presence of magnetization gradient (due to e.g. domain wall) $[8-11]$ $[8-11]$.

Topological insulators (TI) $[12-15]$ $[12-15]$ may be thought as materials with an ultimate spin-orbit coupling. Indeed, the effective Hamiltonian of conduction electrons at the TI surface contains essentially nothing but spin-orbit interaction term that provides a perfect spin-momentum locking. Thus, the magnetization dynamics in a thin ferromagnetic (FM) in a proximity to TI surface is expected to be strongly affected by electric currents and/or electric fields [\[16\]](#page-4-5). There seems to be, indeed, a substantial experimental evidence that the efficiency of domain switching in TI/FM heterostructures is dramatically enhanced as compared to that in metals [\[17](#page-4-6)[–22\]](#page-4-7).

To illustrate generic properties of magnetization dynamics at a TI/FM interface we employ two-dimensional s–d-like model of a Dirac ferromagnet. The advantage of such a model-based microscopic approach is that it is capable of describing complex torques on magnetization arising in TI/FM systems in terms of only few effective parameters. This is in contrast to phenomenological theories that formulate magnetization dynamics in systems with strong spin-orbit coupling in terms of virtually unlimited number of unknown functions [\[23,](#page-4-8) [24\]](#page-4-9). Our results are, therefore, complementary to a number of phe-

FIG. 1. Proposed experimental setup. Non-homogeneous electric field controlled by the top-gate voltage V_{top} induces strong diffusive spin-orbit torque on magnetic moments S in the insulating FM layer from conduction electron spin-density s at the TI surface.

nomenological studies of Dirac ferromagnets [\[25–](#page-4-10)[47\]](#page-4-11).

Microscopic theory of current-induced magnetization dynamics in FM/TI heterostructures has so far been limited to some particular direction of magnetization or to some very specific regimes. In particular, an analytic estimate of spin-transfer and spin-orbit torques in FM/TI bilayer has been given in Ref. [\[48\]](#page-4-12) for magnetization perpendicular to the TI surface. An attempt to generalize these results to arbitrary magnetization direction has been undertaken more recently in Ref. [\[49\]](#page-4-13). However, the non-local behavior of non-equilibrium out-of-plane spin polarization in TI/FM systems that gives rise to magnetization switching effect described in this Letter, have been overlooked in these publications.

The non-local transport on a surface of the TI has been first discussed by Burkov [\[50\]](#page-4-14). The results of this work has been later applied to FM/TI systems [\[51,](#page-4-15) [52\]](#page-4-16) assuming, however, a weak s–d-type exchange coupling between conduction electrons and localized spin subsystems. Such a perturbative treatment still misses out the most interesting regime of equal spin-orbit and s–d exchange interaction strength that corresponds to maximal charge-to-spin conversion.

In this Letter we focus on novel non-local diffusive contribution to the spin-orbit torque on magnetization in FM/TI heterostructures that have been previously ignored. By applying an ac gate voltage V_{top} to a nanograted top-gate as illustrated schematically in Fig. [1](#page-0-0) the diffusive torque can be made so large that it enables magnetization switching to the perpendicular-to-the-plane direction. Thus, the diffusive spin-orbit torque mechanism may provide an efficient route to electric-field control of magnetization in FM/TI films.

To illustrate the effect we employ s–d-like model with the local exchange interaction $H_{\text{ex}} = -J_{\text{sd}} \sum_{n} S_n \cdot c_n^{\dagger} \sigma c_n$ between localized classical magnetic moments S_n on FM lattice (with conserved absolute value $S = |\mathbf{S}_n|$ per unit cell area A) and spin density of conduction electrons (represented by the vector operator $\sigma = (\sigma_x, \sigma_y, \sigma_z)$ on the TI surface) [\[53\]](#page-4-17). Here σ_{α} stand for Pauli matrices and J_{sd} quantifies the s-d-type exchange interaction strength. Below we compute spin-orbit torque and Gilbert damping originating from the conduction electrons under the assumption that the FM layer hosts a single magnetic domain with a direction $m = S/S$.

The classical equation of motion for the unit vector m can be, then, written as

$$
\partial \mathbf{m}/\partial t = -\gamma \, \mathbf{m} \times \mathbf{H}_{\text{eff}} + \mathbf{T}, \quad \mathbf{T} = (J_{\text{sd}} A/\hbar) \, \mathbf{m} \times \mathbf{s}, \tag{1}
$$

where $\hbar = h/2\pi$ is the Planck constant, the first term on the right-hand side represents the combined contribution of external magnetic field and the field produced by neighboring magnetic moments in the FM (due to Heisenberg exchange, for example), while the term T represents the effect of conduction electron spin density $s(r, t) = \langle c_n^{\dagger} \boldsymbol{\sigma} c_n \rangle$ emerging on the TI surface.

The linear response of the non-equilibrium spin-density s to the time derivative $\partial \mathbf{m}/\partial t$ and to the in-plane electric field $\mathbf{E}(\mathbf{r}, t) = E_{\mathbf{q}, \omega} \exp(-i\omega t + i\mathbf{q}\mathbf{r})$ provides us with the Gilbert damping and spin-orbit torque terms, correspondingly. Both responses are computed microscopically from the effective model

$$
H = v [(\boldsymbol{p} - e\boldsymbol{A}) \times \boldsymbol{\sigma}]_z - \Delta_{\rm sd} \boldsymbol{m} \cdot \boldsymbol{\sigma} + V(\boldsymbol{r}), \quad (2)
$$

where $\Delta_{sd} = J_{sd}S$, **A** is the vector potential, $e = -|e|$ is the electron charge, z is the direction perpendicular to the TI surface, v is the effective velocity of Dirac electrons, and $V(r)$ is a disorder potential that models the main relaxation mechanism of conduction electrons. The effective model of Eq. [\(2\)](#page-1-0) describes conduction electrons on the TI surface coupled to FM spins by means of local exchange interaction.

We note, first of all, that the velocity operator in the model of Eq. [\(2\)](#page-1-0) $v = v(\sigma \times \hat{z})$ is simply related to the spin operator σ . As the result, the response of the in-plane spin density $s_{\parallel} = (s_x, s_y)$ to electric field $\mathbf{E} = -\partial \mathbf{A}/\partial t$ is defined by the conductivity tensor [\[49,](#page-4-13) [54\]](#page-4-18). This also means that the non-equilibrium contribution to s_{\parallel} from the electric current density **J** is given by $s_{\parallel} = (\hat{z} \times J)/ev$ irrespective of the scattering mechanisms of conduction electrons and even beyond the linear response. Such a

universal result, however, tells us nothing about the response of s_z component to electric field or current. Such a response plays evidently no role in Eq. [\(1\)](#page-1-1) for $m = \pm \hat{z}$. The s_z component is also vanishing by symmetry if **m** is directed parallel to the TI surface. For $s_z = 0$ the entire spin-orbit torque in the model is the field-like spin-orbit torque, $T_{\text{FL}}^{\text{SOT}} = (J_{\text{sd}}A/\hbar ev) \, \mathbf{m} \times (\hat{\mathbf{z}} \times \mathbf{J})$, which acts in the same way as in-plane external magnetic field applied perpendicular to the charge current.

We will see, however, that for a general direction of S , the perpendicular-to-the-plane component of the electron spin density s_z plays an essential role in magnetization dynamics defined by Eq. [\(1\)](#page-1-1) at small but finite frequencies. Moreover, we demonstrate that the response of s_z to non-homogeneous time-dependent electric field can be large and intrinsically non-local in space and time.

The magnetization switching is facilitated by the Gilbert damping mechanism that brakes down the conservation of the total angular momentum of the localized subsystem. The Gilbert damping (and also spin renormalization) can be extracted from the response of s to the time derivative $\partial \mathbf{m}/\partial t$. It is worth noting that, in our simplistic model [\(2\)](#page-1-0) of TI/FM interface, both the Gilbert damping and spin-orbit torque are naturally related to various spin-spin correlation functions.

Since both the vector potential \boldsymbol{A} and magnetization m couple in Eq. [\(2\)](#page-1-0) to the spin operators, the linear response of s to $\mathbf{E} = -\partial \mathbf{A}/\partial t$ and $\partial \mathbf{m}/\partial t$, is defined in the frequency-momentum domain as

$$
s_{\mathbf{q},\omega} = \frac{1}{v^2 h} \hat{K}(\mathbf{q},\omega) \left[ev\left(\mathbf{E}_{\mathbf{q},\omega} \times \hat{\mathbf{z}}\right) - i\omega \Delta_{\rm sd} \, \mathbf{m}_{\mathbf{q},\omega} \right], \tag{3}
$$

where the dimensionless 9-component tensor $\hat{K}(\boldsymbol{q},\omega)$ is nothing but the spin-spin correlator. The components of \hat{K} are given by the corresponding Kubo formula

$$
\hat{K}_{\alpha\beta}(\boldsymbol{q},\omega) = v^2 \int \frac{d^2 \boldsymbol{p}}{(2\pi)^2} \operatorname{Tr} \left\langle \sigma_\alpha G_{\boldsymbol{p}+\hbar \boldsymbol{q},\varepsilon+\hbar \omega}^{\mathrm{R}} \sigma_\beta G_{\boldsymbol{p},\varepsilon}^{\mathrm{A}} \right\rangle, \tag{4}
$$

which is schematically illustrated in Fig. [2.](#page-2-0) The notation $G_{\boldsymbol{p},\varepsilon}^{\mathrm{R}(\mathrm{A})}$ stands for the retarded (advanced) Green's function for the Hamiltonian of Eq. [\(2\)](#page-1-0), the angular brackets denote disorder averaging, while the energy ε refers to the Fermi energy (zero temperature limit is assumed).

The disorder averaging is performed in Eq. [\(2\)](#page-1-0) for the case of white-noise Gaussian disorder potential

$$
\langle V(\mathbf{r}) \rangle = 0, \quad \langle V(\mathbf{r}) V(\mathbf{r'}) \rangle = 2\pi \alpha (\hbar v)^2 \, \delta(\mathbf{r} - \mathbf{r'}), \quad (5)
$$

characterized by the dimensionless parameter $\alpha \ll 1$. To obtain the results in the leading order with respect to a large metal parameter $\varepsilon \tau \propto 1/\alpha$ (where τ stands for the mean scattering time) one should replace the Green's functions in Eq. [\(4\)](#page-1-2) with the corresponding disorderaveraged Green's functions (the disorder averaging restores translational invariance) in the Born approximation as well as replace one of the spin operators with

FIG. 2. Diagrams considered in the calculation of \hat{K} : (a) noncrossing diagram, (b) X diagram, (c-d) Ψ diagrams. Green areas indicate the ladder summation for the vertex correction in the non-crossing approximation [\[58\]](#page-4-19).

the corresponding vertex corrected spin operator in the non-crossing approximaiton. The vertex corrections play important role for sufficiently low frequencies $\omega \tau_{tr} \ll 1$, where τ_{tr} stands for a characteristic transport scattering time that we specify below.

Despite both responses in Eq. [\(3\)](#page-1-3) are expressed via the same tensor K , there is an important difference in the analysis. Indeed, since we consider a single domain dynamics of FM, we have to take the limit $q \to 0$ in the response to $\partial m/\partial t$ that defines Gilbert damping. On contrary, we assume $\omega \ll Dq^2$ in the response to $\boldsymbol{E}_{\boldsymbol{q},\omega}$ that defines the spin-orbit torque. (Here D stands for the diffusion coefficient that is to be specified below).

The consistent analysis of the responses must also include contributions from rare scattering events, that are not taken into account in the conventional non-crossing approximation. As has been shown in Refs. [\[55](#page-4-20)[–57\]](#page-4-21) the consistent analysis is reduced to the computation of "crossing" diagrams depicted in Fig. [2](#page-2-0) (b-d) in addition to the standard "diffusion ladder" of non-crossing approximation that is indicated by green areas in Fig. [2](#page-2-0) $(see [58]).$ $(see [58]).$ $(see [58]).$

We note that constant in-plane components of magnetization m_x, m_y in Eq. [\(2\)](#page-1-0), which are equivalent to constant in-plane vector potential, can be always excluded from the model by a gauge transform. Consequently, all observable quantities in the model (including all components of \hat{K}) may only depend on the field $\Delta_z = \Delta_{sd} m_z$.

After the gauge transform, the averaged Green's function is given by

$$
G_{\mathbf{p},\varepsilon}^{\mathrm{R}} = \frac{\varepsilon^{\mathrm{R}} + v(\mathbf{p} \times \boldsymbol{\sigma})_z - \Delta_z^{\mathrm{R}} \sigma_z}{(\varepsilon^{\mathrm{R}})^2 - v^2 p^2 - (\Delta_z^{\mathrm{R}})^2},\tag{6}
$$

where ε^{R} and Δ_z^{R} are complex parameters that have to be computed in the Born approximation (which, strictly speaking, has to be applied after the RG analysis [\[55\]](#page-4-20)). The corresponding self-energy

$$
\Sigma^{\mathcal{R}}(\varepsilon) = 2\pi\alpha \, v^2 \! \int \frac{d^2 \mathbf{p}}{(2\pi)^2} G_{\mathbf{p}, \varepsilon}^{\mathcal{R}},\tag{7}
$$

gives rise to the result Im $\Sigma^R = \mp \pi \alpha (\varepsilon - \Delta_z \sigma_z)/2$, which corresponds to the parameters $\varepsilon^{\text{R}} = \varepsilon (1 + i\pi \alpha/2)$ and $\Delta_z^{\rm R} = \Delta_z (1 - i\pi\alpha/2)$ in Eq. [\(6\)](#page-2-1).

After including vertex corrections (both diffusion ladder and additional crossed diagrams) we may cast the result for the spin-spin correlator in the matrix form [\[58\]](#page-4-19)

$$
\hat{K} = \begin{pmatrix} \sigma_{xx} & \sigma_{xy} & Q_y \\ \sigma_{yx} & \sigma_{xx} & -Q_x \\ Q_y & -Q_x & \sigma_{zz} \end{pmatrix},
$$
\n(8)

where σ_{xx} and σ_{xy} are nothing but the conductivity tensor components (measured in the units of e^2/h). The components Q and σ_{zz} were computed without crossed diagrams.

The spin-orbit torque is defined by the first two columns of \hat{K} tensor. By choosing x direction parallel to q vector, we find the conductivity components $[58]$

$$
\sigma_{xx} = \sigma_0, \quad \sigma_{xy} = -\sigma_{yx} = \sigma_H, \quad \sigma_{yy} = \frac{i\omega \,\sigma_0}{i\omega - Dq^2}, \tag{9}
$$

where $D = \hbar v^2 \sigma_0 / \varepsilon$ stands for the diffusion coefficient. The quantities σ_0 and σ_{H} are dimensionless longitudinal and Hall *dc*-conductivities at $q = 0$,

$$
\sigma_0 = \frac{\varepsilon^2 - \Delta_z^2}{\pi \alpha \left(\varepsilon^2 + 3\Delta_z^2\right)}, \qquad \sigma_\text{H} = \frac{8\varepsilon \Delta_z^3}{\left(\varepsilon^2 + 3\Delta_z^2\right)^2}, \qquad (10)
$$

which have been previously computed in Ref. [\[55\]](#page-4-20). It is worth stressing that rare impurity fluctuations (described by the crossed diagrams in Fig. [2\)](#page-2-0) contribute only to the anomalous Hall conductivity σ_H , which is sub-leading in the metal parameter $\alpha \ll 1$ as compared to σ_0 . The results of Eq. [\(9\)](#page-2-2) are obtained in the limit $\omega \tau_{tr} \ll 1$ where $\tau_{tr} = \hbar \varepsilon \sigma_0/(\varepsilon^2 + \Delta_z^2)$ stands for a transport time.

The conductivity components in \hat{K} tensor correspond to the field-like contribution $T_{\rm FL}^{\rm SOT}$ that has been already discussed above. It is interesting to note that one obtains an isotropic conductivity $\sigma_{xx} = \sigma_{yy} = \sigma_0$ only if the limit $q = 0$ is taken before $\omega = 0$. In the opposite case (i.e. for $\omega = 0$ taken first) the conductivity remains anisotropic with respect to the direction of q even for $q = 0$.

The other components contributing to spin-orbit torque are defined by the vector $\mathbf{Q} = (Q_x, Q_y)$, which quantifies the response of s_z spin density to electric field. This contribution is found as [\[58\]](#page-4-19),

$$
\mathbf{Q}(\omega, \mathbf{q}) = \frac{\Delta_z}{\hbar v} \frac{i D \mathbf{q}}{i \omega - Dq^2} \left(1 + \mathcal{O}(\omega \tau_{tr}) \right), \qquad (11)
$$

where we again assumed $\omega \tau_{tr} \ll 1$.

Due to the special role of z direction it is convenient to decompose the vector m to in-plane and perpendicular to the plane components as $m = m_{\parallel} + m_{\perp}$. The result of Eq. [\(11\)](#page-2-3), then, corresponds to an additional diffusive spin-orbit torque of the form

$$
T_{\text{diff}}^{\text{SOT}} = \boldsymbol{m} \times \boldsymbol{m}_{\perp} \int d^2 \bar{\boldsymbol{r}} \int d\bar{t} \, L_{\boldsymbol{r} - \bar{\boldsymbol{r}}, t - \bar{t}} \, \boldsymbol{\nabla}_{\bar{\boldsymbol{r}}} \cdot \boldsymbol{E}(\bar{\boldsymbol{r}}, \bar{t}), \tag{12}
$$

where $\nabla_{\mathbf{r}} \cdot \mathbf{E}(\mathbf{r},t) = \partial_x E_x + \partial_y E_y$ contains only derivatives of in-plane field components and

$$
L_{r,t} = \frac{eJ_{\rm sd}^2 ADS}{2\pi\hbar^3 v^2} \frac{\theta(t)}{4\pi Dt} e^{-r^2/4Dt},\tag{13}
$$

describes electron diffusion. Finite in-plane gradients of electric field can be created by a grated top gate subject to ac voltage as shown in Fig. [1.](#page-0-0) The diffusive spinorbit torque of Eq. [\(12\)](#page-2-4) always corresponds to an effective magnetic field applied in z direction.

To estimate the magnitude of the diffusive torque let us assume that an ac top-gate induces the in-plane field of the form $\mathbf{E}(\mathbf{r}, t) = \hat{\mathbf{x}} E_{\text{gate}} \cos(\omega t - qx)$ with the frequency $\omega \approx 100 \text{ MHz}$ and the characteristic period $2\pi q^{-1} \approx 1 \,\mu \mathrm{m}$. Then, from Eq. [\(12\)](#page-2-4) we readily obtain

$$
\boldsymbol{T}_{\text{diff}}^{\text{SOT}} = \frac{eJ_{\text{sd}}^2ASDE_{gate}}{2\pi\hbar^3 v^2} \frac{q}{\omega^2 + D^2 q^4} \left(Dq^2 \sin(\omega t - qx) - \omega \cos(\omega t - qx) \right) \boldsymbol{m} \times \boldsymbol{m}_{\perp}.
$$
\n(14)

In the limit $\omega \ll Dq^2$ (we take $Dq^2 \approx 100 \text{ GHz}$ for an estimate) we further simplify the expressions as

$$
T_{\text{diff}}^{\text{SOT}} = \frac{J_{\text{sd}}^2 AS}{2\pi \hbar^3 v^2} \frac{eE_{gate}}{q} \sin(\omega t - qx) \mathbf{m} \times \mathbf{m}_{\perp}, \quad (15)
$$

which shows that the diffusive torque lags behind the electric field by a phase $\pi/2$. It is now instructive to compare the strength of the diffusive SOT with that of the field-like SOT (caused by in-plane dc field E_{bias}). Using expressions above one finds that the ratio of the torque amplitudes is given by $T_{\text{diff}}^{\text{SOT}}/T_{\text{FL}}^{\text{SOT}} = \eta E_{\text{gate}}/E_{\text{bias}},$ where $\eta = \Delta_z/\hbar v q \sigma_0$. Note, that E_{gate} can be made much larger than E_{bias} . Moreover, for the system parameters $\sigma_0 \approx 10$, $\Delta_{sd} \approx 0.1$ eV, $v \approx 10^6$ m/s one finds $\eta \sim 1$ (for m directed at 45 degrees to the plane). This estimate, therefore, shows that diffusive torque can be larger or comparable to the field-like torque, thus, providing a possibility to manipulate magnetization direction by an ac gate.

Let us now investigate the response of electron spin density in Eq. [\(3\)](#page-1-3) to the time derivative $\partial \mathbf{m}/\partial t$ (which does not depend on the real space coordinate). Such a response describes both Gilbert damping and spin renormalization. It is easy to see that the response to in-plane time derivative $\partial m_{\parallel}/\partial t$ is, again, expressed through the components of the dc conductivity tensor (10) .

The response to $\partial m_{\perp}/\partial t$ is, however, defined by the spin density-density correlator

$$
\sigma_{zz}(\omega, \mathbf{q} = 0) = \frac{\Delta_z^2}{i\hbar \varepsilon \omega} + \mathcal{O}(\omega \tau_{tr}), \quad (16)
$$

which is computed in the Supplemental Materials [\[58\]](#page-4-19). This expression is readily integrated over time (which is equivalent to multiplication by $-i\omega$), hence it describes constant spin renormalization, which can be omitted. As the result, the Gilbert damping at the TI/FM interface can be cast in the following form

$$
T^{\text{GD}} = \frac{J_{\text{sd}}^2 AS}{\pi \hbar^2 v^2} \, \boldsymbol{m} \times \left(\sigma_0 \, \frac{\partial \boldsymbol{m}_{\parallel}}{\partial t} + \frac{\sigma_{\text{H}}}{m_z} \, \frac{\partial \boldsymbol{m}_{\parallel}}{\partial t} \times \boldsymbol{m}_{\perp} \right), \tag{17}
$$

where the coefficients, σ_0 and σ_H/m_z depend on m_z^2 . Thus, we find that the Gilbert damping tensor is not only anisotropic but also has a non-trivial dependence on the magnetization angle with respect to the plane. We note, that even though Eq. [\(17\)](#page-3-4) does not contain a term proportional to $\partial m_{\perp}/\partial t$, the existing in-plane Gilbert damping is sufficient to relax the magnetization along \hat{z} direction.

The results of Eqs. (12) , (17) have to be substituted into Eq. (1) to obtain the equation of motion for magnetization in the TI/FM system. We remind that, in the case of insulating single-domain ferromagnet layer, the only other term in Eq. (1) is the torque due to effective field H_{eff} that takes into account direct exchange and anisotropy in the FM. Such a field is, however, sensitive neither to electric current nor to the low-frequency gate voltage. It is also worth noting that Eqs. (12) , (17) include only the leading terms in the limit $\omega \tau_{tr} \ll 1$. The expressions beyond the leading order are provided in the Supplementary Material [\[58\]](#page-4-19).

In conclusion, we considered magnetization dynamics in the TI/FM system. We argued that a nonhomogeneous low-frequency ac electric field may induce a strong diffusive spin-orbit torque that is capable of switching FM magnetization in the direction perpendicular to the TI surface (see Eqs. $(11-13)$ $(11-13)$) that represent the main results of the Letter). The diffusive torque does not require a current injection in the TI, while its magnitude can be made larger than that of the field-like torque induced by dc current. Thus, the observation of diffusive torque in TI/FM layers can be important for novel device applications.

We are grateful to O. Gomonay, R. Duine, and J. Sinova for helpful discussions. This research was supported by the JTC-FLAGERA Project GRANS-PORT and by the Dutch Science Foundation NWO/FOM 13PR3118. M.T. acknowledges the support from the Russian Science Foundation under Project 17-12-01359.

- [1] I. M. Miron, G. Gaudin, S. Auffret, B. Rodmacq, A. Schuhl, S. Pizzini, J. Vogel, and P. Gambardella, [Nature Materials](http://dx.doi.org/10.1038/nmat2613) 9, 230 (2010).
- [2] P. M. Haney, H.-W. Lee, K.-J. Lee, A. Manchon, and M. D. Stiles, Phys. Rev. B 87 [\(2013\), 10.1103/Phys-](http://dx.doi.org/ 10.1103/PhysRevB.87.174411)[RevB.87.174411.](http://dx.doi.org/ 10.1103/PhysRevB.87.174411)
- [3] M. I. Dyakonov and V. I. Perel, [Physics Letters A](http://dx.doi.org/10.1016/0375-9601(71)90196-4) 35, [459 \(1971\).](http://dx.doi.org/10.1016/0375-9601(71)90196-4)
- [4] D. Awschalom and N. Samarth, Physics 2, 50 (2009).
- [5] A. Manchon and S. Zhang, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.78.212405) 78 (2008), [10.1103/PhysRevB.78.212405.](http://dx.doi.org/10.1103/PhysRevB.78.212405)
- [6] I. Garate and A. H. MacDonald, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.80.134403) **80** (2009), [10.1103/PhysRevB.80.134403.](http://dx.doi.org/10.1103/PhysRevB.80.134403)
- [7] A. Manchon and S. Zhang, Physical Review B 79, 094422 (2009) .
- [8] J. C. Slonczewski, [J. Magn. Magn. Mater.](http://www.sciencedirect.com/science/article/pii/0304885396000625) 159, L1 [\(1996\).](http://www.sciencedirect.com/science/article/pii/0304885396000625)
- [9] L. Berger, Phys. Rev. B **54**[, 9353 \(1996\).](https://journals.aps.org/prb/abstract/10.1103/PhysRevB.54.9353)
- [10] D. Ralph and M. Stiles, [Journal of Magnetism and Mag](http://dx.doi.org/10.1016/j.jmmm.2007.12.019)[netic Materials](http://dx.doi.org/10.1016/j.jmmm.2007.12.019) 320, 1190 (2008).
- [11] M. D. Stiles and A. Zangwill, [Physical Review B](http://dx.doi.org/10.1103/PhysRevB.66.014407) 66, [014407 \(2002\).](http://dx.doi.org/10.1103/PhysRevB.66.014407)
- [12] L. Fu, C. L. Kane, and E. J. Mele, [Physical Review](http://dx.doi.org/10.1103/PhysRevLett.98.106803) Letters 98[, 106803 \(2007\).](http://dx.doi.org/10.1103/PhysRevLett.98.106803)
- [13] J. E. Moore and L. Balents, [Physical Review B](http://dx.doi.org/10.1103/PhysRevB.75.121306) 75, [121306 \(2007\).](http://dx.doi.org/10.1103/PhysRevB.75.121306)
- [14] R. Roy, [Physical Review B](http://dx.doi.org/10.1103/PhysRevB.79.195322) 79, 195322 (2009).
- [15] D. Hsieh, D. Qian, L. Wray, Y. Xia, Y. S. Hor, R. J. Cava, and M. Z. Hasan, Nature 452[, 970 \(2008\).](http://dx.doi.org/10.1038/nature06843)
- [16] X.-L. Qi, T. L. Hughes, and S.-C. Zhang, [Nature Physics](http://dx.doi.org/10.1038/nphys913) 4[, 273 \(2008\).](http://dx.doi.org/10.1038/nphys913)
- [17] A. R. Mellnik, J. S. Lee, A. Richardella, J. L. Grab, P. J. Mintun, M. H. Fischer, A. Vaezi, A. Manchon, E.-A. Kim, N. Samarth, and D. C. Ralph, [Nature](http://dx.doi.org/10.1038/nature13534) 511, 449 $(2014).$
- [18] Y. Wang, P. Deorani, K. Banerjee, N. Koirala, M. Brahlek, S. Oh, and H. Yang, [Phys. Rev. Lett.](http://dx.doi.org/10.1103/PhysRevLett.114.257202) 114, [257202 \(2015\).](http://dx.doi.org/10.1103/PhysRevLett.114.257202)
- [19] Y. Fan, P. Upadhyaya, X. Kou, M. Lang, S. Takei, Z. Wang, J. Tang, L. He, L.-T. Chang, M. Montazeri, G. Yu, W. Jiang, T. Nie, R. N. Schwartz, Y. Tserkovnyak, and K. L. Wang, [Nature Materials](http://dx.doi.org/10.1038/nmat3973) 13, 699 (2014).
- [20] Y. Fan, X. Kou, P. Upadhyaya, Q. Shao, L. Pan, M. Lang, X. Che, J. Tang, M. Montazeri, K. Murata, L.- T. Chang, M. Akyol, G. Yu, T. Nie, K. L. Wong, J. Liu, Y. Wang, Y. Tserkovnyak, and K. L. Wang, [Nature Nan](http://dx.doi.org/10.1038/nnano.2015.294)otechnology 11[, 352 EP \(2016\).](http://dx.doi.org/10.1038/nnano.2015.294)
- [21] K. Yasuda, A. Tsukazaki, R. Yoshimi, K. Kondou, K. S. Takahashi, Y. Otani, M. Kawasaki, and Y. Tokura, [Phys.](http://dx.doi.org/ 10.1103/PhysRevLett.119.137204) Rev. Lett. 119[, 137204 \(2017\).](http://dx.doi.org/ 10.1103/PhysRevLett.119.137204)
- [22] S. Cha, M. Noh, J. Kim, J. Son, H. Bae, D. Lee, H. Kim, J. Lee, H.-S. Shin, S. Sim, S. Yang, S. Lee, W. Shim, C.- H. Lee, M.-H. Jo, J. S. Kim, D. Kim, and H. Choi, [Na](http://dx.doi.org/10.1038/s41565-018-0195-y)[ture Nanotechnology \(2018\), 10.1038/s41565-018-0195](http://dx.doi.org/10.1038/s41565-018-0195-y) [y.](http://dx.doi.org/10.1038/s41565-018-0195-y)
- [23] E. van der Bijl and R. A. Duine, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.86.094406) 86, 094406 [\(2012\).](http://dx.doi.org/10.1103/PhysRevB.86.094406)
- [24] K. M. D. Hals and A. Brataas, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.88.085423) 88, 085423 [\(2013\).](http://dx.doi.org/10.1103/PhysRevB.88.085423)
- [25] Y. Tserkovnyak and C. H. Wong, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.79.014402) 79, [014402 \(2009\).](http://dx.doi.org/10.1103/PhysRevB.79.014402)
- [26] F. Mahfouzi, N. Nagaosa, and B. K. Nikolić, [Physical Review Letters](http://dx.doi.org/10.1103/PhysRevLett.109.166602) 109 (2012), 10.1103/Phys-[RevLett.109.166602.](http://dx.doi.org/10.1103/PhysRevLett.109.166602)
- [27] Y. Ferreiros, F. J. Buijnsters, and M. I. Katsnelson, Phys. Rev. B 92[, 085416 \(2015\).](http://dx.doi.org/10.1103/PhysRevB.92.085416)
- [28] M. H. Fischer, A. Vaezi, A. Manchon, and E.- A. Kim, Physical Review B 93 [\(2016\), 10.1103/Phys-](http://dx.doi.org/10.1103/PhysRevB.93.125303)

[RevB.93.125303,](http://dx.doi.org/10.1103/PhysRevB.93.125303) [arXiv:1305.1328.](http://arxiv.org/abs/1305.1328)

- [29] T. Yokoyama, J. Zang, and N. Nagaosa, [Physical Review](http://dx.doi.org/10.1103/PhysRevB.81.241410) B 81 [\(2010\), 10.1103/PhysRevB.81.241410.](http://dx.doi.org/10.1103/PhysRevB.81.241410)
- [30] T. Yokoyama, [Physical Review B](http://dx.doi.org/10.1103/PhysRevB.84.113407) 84, 113407 (2011).
- [31] Z. B. Siu, H. C. Son, M. b. A. Jalil, and S. G. Tan, [arXiv:1609.02242 \[cond-mat\] \(2016\),](http://arxiv.org/abs/1609.02242) [arXiv:1609.02242](http://arxiv.org/abs/1609.02242) [\[cond-mat\].](http://arxiv.org/abs/1609.02242)
- [32] F. Mahfouzi, B. K. Nikolić, and N. Kioussis, [Physical](http://dx.doi.org/10.1103/PhysRevB.93.115419) Review B 93 [\(2016\), 10.1103/PhysRevB.93.115419.](http://dx.doi.org/10.1103/PhysRevB.93.115419)
- [33] M. Soleimani, S. Jalili, F. Mahfouzi, and N. Kioussis, [EPL \(Europhysics Letters\)](http://dx.doi.org/10.1209/0295-5075/117/37001) 117, 37001 (2017).
- [34] D. Kurebayashi and K. Nomura, [arXiv:1702.04918 \[cond](http://arxiv.org/abs/1702.04918)[mat\] \(2017\),](http://arxiv.org/abs/1702.04918) [arXiv:1702.04918 \[cond-mat\].](http://arxiv.org/abs/1702.04918)
- [35] J. Chen, Y. Peng, and J. Zhou, [Journal of Magnetism](http://dx.doi.org/ 10.1016/j.jmmm.2017.02.043) [and Magnetic Materials](http://dx.doi.org/ 10.1016/j.jmmm.2017.02.043) 432, 554 (2017).
- [36] M. Rodriguez-Vega, G. Schwiete, J. Sinova, and E. Rossi, [arXiv:1610.04229 \[cond-mat\] \(2016\),](http://arxiv.org/abs/1610.04229) [arXiv:1610.04229](http://arxiv.org/abs/1610.04229) [\[cond-mat\].](http://arxiv.org/abs/1610.04229)
- [37] X.-L. Qi, T. L. Hughes, and S.-C. Zhang, [Physical Re](http://dx.doi.org/10.1103/PhysRevB.78.195424)view B 78[, 195424 \(2008\).](http://dx.doi.org/10.1103/PhysRevB.78.195424)
- [38] I. Garate and M. Franz, [Physical Review Letters](http://dx.doi.org/10.1103/PhysRevLett.104.146802) 104, [146802 \(2010\).](http://dx.doi.org/10.1103/PhysRevLett.104.146802)
- [39] K. Nomura and N. Nagaosa, [Physical Review B](http://dx.doi.org/10.1103/PhysRevB.82.161401) 82, [161401 \(2010\).](http://dx.doi.org/10.1103/PhysRevB.82.161401)
- [40] Y. Tserkovnyak and D. Loss, [Physical Review Letters](http://dx.doi.org/10.1103/PhysRevLett.108.187201) 108 [\(2012\), 10.1103/PhysRevLett.108.187201.](http://dx.doi.org/10.1103/PhysRevLett.108.187201)
- [41] J. Linder, [Physical Review B](http://dx.doi.org/10.1103/PhysRevB.90.041412) **90**, 041412 (2014).
- [42] Y. Tserkovnyak, D. A. Pesin, and D. Loss, [Physical Re](http://dx.doi.org/10.1103/PhysRevB.91.041121)view B 91[, 041121 \(2015\).](http://dx.doi.org/10.1103/PhysRevB.91.041121)
- [43] H. T. Ueda, A. Takeuchi, G. Tatara, and T. Yokoyama, [Physical Review B](http://dx.doi.org/ 10.1103/PhysRevB.85.115110) 85, 115110 (2012).
- [44] X. Liu and J. Sinova, [Physical Review Letters](http://dx.doi.org/10.1103/PhysRevLett.111.166801) 111, [166801 \(2013\).](http://dx.doi.org/10.1103/PhysRevLett.111.166801)
- [45] P.-H. Chang, T. Markussen, S. Smidstrup, K. Stokbro, and B. K. Nikolić, *[Physical Review B](http://dx.doi.org/10.1103/PhysRevB.92.201406)* **92**, 201406 (2015).
- [46] J. Fujimoto and H. Kohno, [Physical Review B](http://dx.doi.org/10.1103/PhysRevB.90.214418) **90**, 214418 [\(2014\).](http://dx.doi.org/10.1103/PhysRevB.90.214418)
- [47] N. Okuma and M. Ogata, [Physical Review B](http://dx.doi.org/10.1103/PhysRevB.93.140205) **93**, 140205 [\(2016\).](http://dx.doi.org/10.1103/PhysRevB.93.140205)
- [48] A. Sakai and H. Kohno, [Physical Review B](http://dx.doi.org/10.1103/PhysRevB.89.165307) 89 (2014), [10.1103/PhysRevB.89.165307.](http://dx.doi.org/10.1103/PhysRevB.89.165307)
- [49] P. B. Ndiaye, C. A. Akosa, M. H. Fischer, A. Vaezi, E.- A. Kim, and A. Manchon, [Physical Review B](http://dx.doi.org/ 10.1103/PhysRevB.96.014408) 96 (2017), [10.1103/PhysRevB.96.014408.](http://dx.doi.org/ 10.1103/PhysRevB.96.014408)
- [50] A. A. Burkov and D. G. Hawthorn, [Physical Review Let](http://dx.doi.org/10.1103/PhysRevLett.105.066802)ters 105[, 066802 \(2010\).](http://dx.doi.org/10.1103/PhysRevLett.105.066802)
- [51] K. Taguchi, K. Shintani, and Y. Tanaka, [Physical Re](http://dx.doi.org/10.1103/PhysRevB.92.035425)view B 92 [\(2015\), 10.1103/PhysRevB.92.035425.](http://dx.doi.org/10.1103/PhysRevB.92.035425)
- [52] K. Shintani, K. Taguchi, Y. Tanaka, and Y. Kawaguchi, [Physical Review B](http://dx.doi.org/ 10.1103/PhysRevB.93.195415) 93, 195415 (2016).
- [53] S. V. Vonsovsky, *Magnetism* (Wiley, New York, 1974).
- [54] S. Ghosh and A. Manchon, [Phys. Rev. B](http://dx.doi.org/10.1103/PhysRevB.97.134402) 97, 134402 [\(2018\).](http://dx.doi.org/10.1103/PhysRevB.97.134402)
- [55] I. A. Ado, I. A. Dmitriev, P. M. Ostrovsky, and M. Titov, [EPL \(Europhysics Letters\)](http://dx.doi.org/10.1209/0295-5075/111/37004) 111, 37004 (2015).
- [56] I. A. Ado, I. A. Dmitriev, P. M. Ostrovsky, and M. Titov, [Phys. Rev. Lett.](http://dx.doi.org/10.1103/PhysRevLett.117.046601) 117, 046601 (2016).
- [57] I. A. Ado, I. A. Dmitriev, P. M. Ostrovsky, and M. Titov, Phys. Rev. B 96[, 235148 \(2017\).](http://dx.doi.org/10.1103/PhysRevB.96.235148)
- [58] see Supplementary Material,.

ONLINE SUPPLEMENTARY MATERIAL

Non-local spin-orbit torque at a surface of topological insulator

R. J. Sokolewicz, I. A. Ado, M. I. Katsnelson, P. M. Ostrovsky and M. Titov

In this Supplementary Material we provide main technical details of the analytical calculation.

I. KUBO FORMULA

The linear response formula used in the Letter can be obtained in a Keldysh-framework. We start by introducing the Green function $\mathcal G$ in rotated Keldysh space [see e.g. J. Rammer and H. Smith. Rev. Mod. Phys. 58, 323 (1986)]

$$
\mathcal{G} = \begin{pmatrix} G^{\rm R} & G^{\rm K} \\ 0 & G^{\rm A} \end{pmatrix} \tag{s1}
$$

where R, A and K denote retarded, advanced and Keldysh Green functions respectively. In this notation a perturbation to a classical field $V(\boldsymbol{x}, t)$ is given by

$$
\delta\mathcal{G}(\boldsymbol{x}_1,t_1;\boldsymbol{x}_2,t_2) = \int d\boldsymbol{x}_3 \int dt_3 \, \mathcal{G}^{(0)}(\boldsymbol{x}_1,t_1;\boldsymbol{x}_3,t_3) \hat{V}(\boldsymbol{x}_3,t_3) \mathcal{G}^{(0)}(\boldsymbol{x}_3,t_3;\boldsymbol{x}_2,t_2) + \mathcal{O}(V^2)
$$
(s2)

with $\mathcal{G}^{(0)}$ equilibrium Green functions. The Wigner-transform of a function $F(\boldsymbol{x}_1,t_1;\boldsymbol{x}_2,t_2)$ is given by

$$
F(\boldsymbol{x}_1, t_1; \boldsymbol{x}_2, t_2) = \int \frac{d^2 \boldsymbol{p}}{(2\pi\hbar)^2} \int \frac{d\varepsilon}{2\pi\hbar} e^{-i\varepsilon(t_1 - t_2)/\hbar} e^{i\boldsymbol{p}\cdot(\boldsymbol{x}_1 - \boldsymbol{x}_2)/\hbar} F(\varepsilon, \boldsymbol{p}, R, T)
$$
(s3)

with energy ε , momentum p , time $T = \frac{t_1+t_2}{2}$ and position $\mathbf{R} = \frac{\mathbf{x}_1+\mathbf{x}_2}{2}$. In equilibrium the Green functions $\mathcal{G}^{(0)}$ do not depend on R and T, so that the momentum-frequency representation of Eq. [\(s2\)](#page-5-0) becomes $\delta \mathcal{G}(\varepsilon,\omega,\bm{p},\bm{q})=$ $\mathcal{G}^{(0)}_{\varepsilon_+,p_+}V_{\omega,q}\mathcal{G}^{(0)}_{\varepsilon_-,q_-}$, with subscripts $\varepsilon_\pm=\varepsilon\pm\hbar\omega/2$ and $\boldsymbol{p}_\pm=\boldsymbol{p}\pm\hbar\boldsymbol{q}/2$ and $V_{\omega,q}$ the Fourier transform of $V(\boldsymbol{R},T)$. The spin density $s_{\omega,q}$ is given by

$$
\mathbf{s}_{\omega,\mathbf{q}} = i\hbar \int \frac{d\varepsilon}{2\pi\hbar} \int \frac{d^2\mathbf{p}}{(2\pi\hbar)^2} \operatorname{Tr} \left[\delta G^<(\varepsilon, T)\mathbf{\sigma} \right], \ \ \delta G^<(\varepsilon, \omega, \mathbf{p}, \mathbf{q}) = 1/2(\delta G^{\mathrm{K}}(\varepsilon, \omega, \mathbf{p}, \mathbf{q}) - \delta G^{\mathrm{R}}(\varepsilon, \omega, \mathbf{p}, \mathbf{q}) + \delta G^{\mathrm{A}}(\varepsilon, \omega, \mathbf{p}, \mathbf{q}). \tag{84}
$$

In equilibrium we have the fluctuation-dissipation theorem $G_{\varepsilon_{\pm},\mathbf{p}_{\pm}}^{\mathrm{K}} = (1-2f_{\varepsilon_{\pm}})(G_{\varepsilon_{\pm},\mathbf{p}_{\pm}}^{\mathrm{R}} - G_{\varepsilon_{\pm},\mathbf{p}_{\pm}}^{\mathrm{A}})$ with $f_{\varepsilon_{\pm}}$ the Fermi distribution, so that the spin density now becomes

$$
s_{\omega,q} = i\hbar \int \frac{d\varepsilon}{2\pi\hbar} \int \frac{d^2\mathbf{p}}{(2\pi\hbar)^2} \operatorname{Tr}\langle -(f_{\varepsilon_+} - f_{\varepsilon_-})\boldsymbol{\sigma} G^{\rm R}_{\varepsilon_+, \mathbf{p}_+} V_{\omega, \mathbf{q}} G^{\rm A}_{\varepsilon_-, \mathbf{p}_-} - f_{\varepsilon_+} \boldsymbol{\sigma} G^{\rm R}_{\varepsilon_+, \mathbf{p}_+} V_{\omega, \mathbf{q}} G^{\rm R}_{\varepsilon_-, \mathbf{p}_-} + f_{\varepsilon_-} \boldsymbol{\sigma} G^{\rm A}_{\varepsilon_+, \mathbf{p}_+} V_{\omega, \mathbf{q}} G^{\rm A}_{\varepsilon_-, \mathbf{p}_-} \rangle, \tag{S5}
$$

where the angular brackets stands for impurity averaging. The latter amounts to the replacement of the Green's functions with the corresponding impurity averaged Greens functions (in Born approximation) and to the replacement of one of the spin operators with the corresponding vertex corrected operator (in the non-crossing approximation). The corrections beyond the non-crossing approximation are important for those tensor components that lack leadingorder contribution [\[55\]](#page-4-20). To keep our notations more compact we ignore here the fact that the Green's functions before disorder averaging lack translational invariance, i. e. depend on both Wigner coordinates: momentum and coordinate.

In the limit of small frequency, i.e. $\hbar\omega \ll \varepsilon$, we obtain

$$
s_{\alpha} = s_{\alpha}^{\text{I}} + s_{\alpha}^{\text{II}},\tag{86}
$$

$$
s_{\alpha}^{\text{I}} = \frac{i\omega}{2\hbar} \int \frac{d\varepsilon}{2\pi} \int \frac{d^2\mathbf{p}}{(2\pi)^2} \left(-\frac{\partial f}{\partial_{\varepsilon}} \right) \text{Tr} \left\langle 2\sigma_{\alpha} G^{\text{R}}_{\varepsilon_+, \mathbf{p}_+} V_{\omega, \mathbf{q}} G^{\text{A}}_{\varepsilon_-, \mathbf{p}_-} - \sigma_{\alpha} G^{\text{A}}_{\varepsilon_+, \mathbf{p}_+} V_{\omega, \mathbf{q}} G^{\text{A}}_{\varepsilon_-, \mathbf{p}_-} - \sigma_{\alpha} G^{\text{R}}_{\varepsilon_+, \mathbf{p}_+} V_{\omega, \mathbf{q}} G^{\text{R}}_{\varepsilon_-, \mathbf{p}_-} \right\rangle, \quad (87)
$$

$$
s_{\alpha}^{\text{II}} = \frac{i}{\hbar} \int \frac{d\varepsilon}{2\pi} \int \frac{d^2 \mathbf{p}}{(2\pi)^2} f_{\varepsilon} \operatorname{Tr} \left\langle \sigma_{\alpha} G_{\varepsilon_+, \mathbf{p}_+}^{\text{A}} V_{\omega, \mathbf{q}} G_{\varepsilon_-, \mathbf{p}_-}^{\text{A}} - \sigma_{\alpha} G_{\varepsilon_+, \mathbf{p}_+}^{\text{R}} V_{\omega, \mathbf{q}} G_{\varepsilon_-, \mathbf{p}_-}^{\text{R}} \right\rangle, \tag{88}
$$

where s^I and s^{II} are the Kubo and Streda contributions respectively. The Streda contribution is sub-leading in the powers of weak disorder strength $\alpha \ll 1$ as far as the Fermi energy lies outside the gap. Similarly, the AA and RR

bubbles in the expression of s^I_α are sub-leading and may be neglected. Furthermore, we work in the zero temperature limit.

With these considerations together with $V_{\omega,q} = -ev(\mathbf{A} \times \boldsymbol{\sigma})_z - \Delta_{sd} \boldsymbol{m} \cdot \boldsymbol{\sigma}$, we obtain

$$
s_{\mathbf{q},\omega} = \frac{1}{v^2 h} \hat{K}(\mathbf{q},\omega) [ev(\mathbf{E}_{\mathbf{q},\omega} \times \hat{\mathbf{z}}) - i\omega \Delta_{\rm sd} \mathbf{m}_{\omega}], \ \ \hat{K}_{\alpha\beta}(\mathbf{q},\omega) = v^2 \int \frac{d^2 \mathbf{p}}{(2\pi)^2} \operatorname{Tr} \langle \sigma_{\alpha} G_{\mathbf{p}+\hbar q,\varepsilon+\hbar \omega}^{\rm R} \sigma_{\beta} G_{\mathbf{p},\varepsilon}^{\rm A} \rangle, \tag{S9}
$$

which correspond to Eqs. [\(3](#page-1-3)[,4\)](#page-1-2) of the main text. Here we used $E_{q,\omega} = i\omega A_{q,\omega}$.

II. CALCULATION OF THE SPIN-SPIN CORRELATOR

The spin polarization $s_{a,\omega}$ needs to be averaged over many disorder realizations. In the Born approximation we replace each Green's function in Eq. [\(s9\)](#page-6-0) with a disorder averaged one and replace one of the spin-operators with a vertex corrected spin operator. When calculating the components of $K_{\alpha\beta}$ that are of the order $\mathcal{O}(\varepsilon\tau)^0$, one should also include contributions from rare-scattering events. This is done by including the crossed diagrams depicted Figure [2](#page-2-0) of the main text.

The disorder-averaged Green functions are obtained by including the Born self-energy $\Sigma^{R(A)}$ (we set $\hbar = 1$ in the subsequent formulas)

$$
\Sigma^{\mathcal{R}(\mathcal{A})} = 2\pi\alpha v^2 \int \frac{d^2 \mathbf{p}}{(2\pi)^2} \left(\varepsilon - H - \Sigma^{\mathcal{R}(\mathcal{A})}\right)^{-1},\tag{s10}
$$

whose imaginary parts are (to the leading order in $1/\alpha$) given by Im $\Sigma^{\text{R(A)}} = \pm \frac{\pi \alpha}{2} (\varepsilon \sigma_0 - \Delta_z \sigma_3)$. The real part of $\Sigma^{\text{R(A)}}$ lead to renormalization of ε and Δ_{sd} . In the following we keep the same notation for ε and Δ_z , though now they correspond to renormalized quantities. The Green functions are then given by

$$
G_{\varepsilon,\mathbf{p}}^{\text{R(A)}} = \frac{\varepsilon^{\text{R(A)}} \sigma_0 + v (\mathbf{p} \times \boldsymbol{\sigma})_z - \Delta_z^{\text{R(A)}} \sigma_3}{(\varepsilon^{\text{R(A)}})^2 - v^2 p^2 - (\Delta_z^{\text{R(A)}})^2}
$$
(s11)

where $\varepsilon^{R(A)} = \varepsilon (1 \pm i\pi\alpha/2)$ and $\Delta_z^{R(A)} = \Delta_z (1 \mp i\pi\alpha/2)$. The m_{\parallel} components were removed via the gauge transformation.

Next, we need to replace the spin operator with a vertex corrected spin operator in the ladder approximation,

$$
\sigma_{\alpha} \left(= \sigma_{\alpha} \left(+ \sigma_{\alpha} \left(\cdot, \cdot \right) \right) \tag{812}
$$

where, the dressing of σ_{α} with a single disorder line is defined by

$$
\sigma_{\alpha} \bigg(\frac{1}{2} = 2\pi \alpha v^2 \int \frac{d^2 p}{(2\pi)^2} G_{\varepsilon + \omega, p+q}^A \sigma_{\alpha} G_p^R = \pi \alpha M_{\alpha\beta} \sigma_{\beta}, \tag{813}
$$

with $M_{\alpha\beta} = v^2 \int d^2p \,\text{Tr} \left[\sigma_\alpha G_{\varepsilon+\omega,\bm{p}+\bm{q}}^R \sigma_\beta G_{\varepsilon,\bm{p}}^A \right] / (2\pi)^2$. The ladder summation is conveniently represented in the matrix form by introducing a matrix M^{\dot{M}} with 16 components $M_{\alpha\beta}$ for $\alpha, \beta = 0, x, y, z$ ($\sigma_0 = 1$). We stress that, in the computation of vertex correction, we are interested only in the leading order contributions to $M_{\alpha\beta}$ that are of the order of $1/\alpha$. The sub-leading contributions to M_{00} and M_{zz} components suffer from a logarithmic divergency at large momenta. In our calculation the terms of the order of $\alpha \ln p_{\text{cutoff}}/\varepsilon$ (where p_{cutoff} is the ultraviolet momentum cut-off, is, therefore, disregarded with respect to 1. This approximation is legitimate since we assume that all model parameters ϵ , Δ_{sd} and α are first renormalized such that $p_{\text{cutoff}} \approx \varepsilon$.

It is, then, easy to see that the vertex-corrected spin operator is readily obtained from the geometric series of powers of $\pi \alpha M$,

$$
\sigma_{\alpha} \left(\sigma_{\alpha} + \pi \alpha \hat{M}_{\alpha\beta} \sigma_{\beta} + (\pi \alpha)^2 (\hat{M}^2)_{\alpha\beta} \sigma_{\beta} + \dots = \left[1 - \pi \alpha \hat{M} \right]_{\alpha\beta}^{-1} \sigma_{\beta}, \tag{814}
$$

where the summation of the repeating index $\beta = 0, x, y, z$ is assumed.

Thus, in the non-crossing approximation (see Figure [2a](#page-2-0) of the main text), one simply finds $\hat{K} = \hat{M} [1 - \pi \alpha \hat{M}]^{-1}$. Dressed spin-spin correlators are defined by the components $\hat{K}_{\alpha\beta}$ with $\alpha, \beta = x, y, z$.

The crossed diagrams in Figure [2](#page-2-0) (b-d) of the main text give a contribution to the components of \tilde{K} of the order $\mathcal{O}(\alpha^0)$. The only components that are modified to this order are those corresponding to the Hall conductivity (i.e. $\alpha, \beta = 1, 2$ and vice versa). Details of this calculation can be found in Ref. [\[55\]](#page-4-20).

We shall compute the matrix \hat{M} to the second order in powers of ω and q. The result is represented in the form $M = M_0 + M_{\omega} + M_{\omega^2} + M_{q\omega} + M_{q^2}$, where

$$
M_0 = \frac{1}{\pi \alpha (\varepsilon^2 + \Delta_z^2)} \begin{pmatrix} \varepsilon^2 & 0 & 0 & -\varepsilon \Delta_z \\ 0 & (\varepsilon^2 - \Delta_z^2)/2 & \pi \alpha \varepsilon \Delta_z & 0 \\ 0 & -\pi \alpha \varepsilon \Delta_z & (\varepsilon^2 - \Delta_z^2)/2 & 0 \\ -\varepsilon \Delta_z & 0 & 0 & \Delta_z^2 \end{pmatrix},
$$
(s15a)

$$
M_{\omega} = \frac{i\omega\varepsilon}{\left[\pi\alpha(\varepsilon^2 + \Delta_z^2)\right]^2} \begin{pmatrix} \varepsilon^2 & 0 & 0 & -\varepsilon\Delta_z\\ 0 & (\varepsilon^2 - \Delta_z^2)/2 & \pi\alpha(\varepsilon^2 - \Delta_z^2)\Delta_z/2\varepsilon & 0\\ 0 & -\pi\alpha(\varepsilon^2 - \Delta_z^2)\Delta_z/2\varepsilon & (\varepsilon^2 - \Delta_z^2)/2 & 0\\ -\varepsilon\Delta_z & 0 & 0 & \Delta_z^2 \end{pmatrix},
$$
(s15b)

$$
M_{\omega^2} = \frac{(i\omega\varepsilon)^2}{\left[\pi\alpha(\varepsilon^2 + \Delta_z^2)\right]^3} \begin{pmatrix} \varepsilon^2 & 0 & 0 & -\varepsilon\Delta_z\\ 0 & (\varepsilon^2 - \Delta_z^2)/2 & \pi\alpha(\varepsilon^2 - \Delta_z^2)\Delta_z/2\varepsilon & 0\\ 0 & -\pi\alpha(\varepsilon^2 - \Delta_z^2)\Delta_z/2\varepsilon & (\varepsilon^2 - \Delta_z^2)/2 & 0\\ -\varepsilon\Delta_z & 0 & 0 & \Delta_z^2 \end{pmatrix},
$$
(s15c)

$$
M_{q\omega} = \frac{v(\varepsilon^2 - \Delta_z^2)}{\left[\pi\alpha\left(\varepsilon^2 + \Delta_z^2\right)\right]^2} \left(\frac{-i}{2} + \frac{\varepsilon\omega}{\left[\pi\alpha\left(\varepsilon^2 + \Delta_z^2\right)\right]}\right) \begin{pmatrix} 0 & \varepsilon q_x & \varepsilon q_y & 0\\ \varepsilon q_x & 0 & 0 & -\Delta_z q_x\\ \varepsilon q_y & 0 & 0 & -\Delta_z q_y\\ 0 & -\Delta_z q_x & -\Delta_z q_y & 0 \end{pmatrix},\tag{815d}
$$

$$
M_{q^2} = \frac{v^2(\varepsilon^2 - \Delta_z^2)}{2\left[\pi\alpha(\varepsilon^2 + \Delta_z^2)\right]^3} \begin{pmatrix} \varepsilon^2 q^2 & 0 & 0 & -\varepsilon\Delta_z q^2\\ 0 & -(\varepsilon^2 - \Delta_z^2)(3q_x^2 - q_y^2)/4 & -(\varepsilon^2 - \Delta_z^2)q_xq_y/2 & 0\\ 0 & -(\varepsilon^2 - \Delta_z^2)q_xq_y/2 & -(\varepsilon^2 - \Delta_z^2)(3q_y^2 - q_x^2)/4 & 0\\ -\varepsilon\Delta_z q^2 & 0 & 0 & \Delta_z^2 q^2 \end{pmatrix} .
$$
 (s15e)

Using the result for M we, then, compute the tensor \hat{K} as

$$
\hat{K} = \begin{pmatrix} \sigma_{xx} & \sigma_{xy} & Q_y \\ \sigma_{yx} & \sigma_{yy} & -Q_x \\ Q_y & -Q_x & \sigma_{zz} \end{pmatrix} . \tag{816}
$$

Complete expressions for σ_{ij} and \boldsymbol{Q} are cumbersome. We proceed by analyzing the denominator of the components of \hat{K} , which is proportional to det $[1 - \pi \alpha M]$

$$
\det[1 - \pi \alpha M] = -\frac{\varepsilon \left(\varepsilon^2 + 3\Delta_z^2\right)^2}{4\pi \alpha \left(\varepsilon^2 + \Delta_z^2\right)^3} \times \left(i\omega \left(1 - i\omega \tau_{\text{tr}} \frac{\varepsilon^2 - 5\Delta_z^2}{\varepsilon^2 - \Delta_z^2} + \mathcal{O}((\omega \tau_{\text{tr}})^2)\right)\n- Dq^2 \left(1 + i\omega \tau_{\text{tr}} \frac{13\Delta_z^4 + 10\Delta_z^2 \varepsilon^2 + \varepsilon^4}{(\varepsilon^2 - \Delta_z^2)(\varepsilon^2 + \Delta_z^2)} - (i\omega \tau_{\text{tr}})^2 \frac{(\varepsilon^2 + 3\Delta^2)(\varepsilon^4 - 14\varepsilon^2 \Delta_z - 35\Delta_z^4)}{(\varepsilon^2 - \Delta_z^2)(\varepsilon^2 + \Delta_z^2)} + \mathcal{O}((\omega \tau_{\text{tr}})^3)\right) + \mathcal{O}((Dq^2)^2 \tau_{\text{tr}})\right)
$$
\n(8.17)

where $D = v^2 \sigma_0 / \varepsilon$ stands for the diffusion coefficient, $\tau_{tr} = \varepsilon \sigma_0 / (\varepsilon^2 + \Delta_z^2)$ for the transport time and σ_0 the xx component of the conductivity tensor [\[55\]](#page-4-20). By restricting ourselves to perturbations that vary slow in time compared to the transport time τ_{tr} and smooth in space compared to the diffusion length $L_D = \sqrt{D\tau_{tr}}$, i.e. $\omega\tau_{tr} Dq^2\tau_{tr} \ll 1$, we are able to extract the diffusion pole $(i\omega - Dq^2)^{-1}$.

The components of the conductivity tensor $\hat{\sigma}$ at finite ω and q are given by

$$
\sigma_{xx} = \sigma_0 + \frac{Dq^2}{i\omega - Dq^2} \left(\frac{q_y^2}{q^2} \sigma_0 - i\omega \tau_{\rm tr} \left(\frac{2}{\pi \alpha} \frac{\varepsilon^2 + 2\Delta_z^2}{\varepsilon^2 + \Delta_z^2} + \frac{3}{\pi \alpha} \frac{q_x^2 - q_y^2}{2q^2} \right) \right)
$$
(s18a)

$$
\sigma_{yy} = \sigma_0 + \frac{Dq^2}{i\omega - Dq^2} \left(\frac{q_x^2}{q^2} \sigma_0 - i\omega \tau_{\rm tr} \left(\frac{2}{\pi \alpha} \frac{\varepsilon^2 + 2\Delta_z^2}{\varepsilon^2 + \Delta_z^2} - \frac{3}{\pi \alpha} \frac{q_x^2 - q_y^2}{2q^2} \right) \right)
$$
(s18b)

$$
\sigma_{xy} = \sigma_{\rm H} + \frac{Dq^2}{i\omega - Dq^2} \left(-\frac{q_x q_y}{q^2} \sigma_0 - i\omega \tau_{\rm tr} \frac{3}{\pi \alpha} \frac{q_x q_y}{q^2} \right)
$$
(s18c)

$$
\sigma_{yx} = -\sigma_H + \frac{Dq^2}{i\omega - Dq^2} \left(-\frac{q_x q_y}{q^2} \sigma_0 - i\omega \tau_{\rm tr} \frac{3}{\pi \alpha} \frac{q_x q_y}{q^2} \right), \tag{s18d}
$$

where σ_0 and σ_H are given in Eq. [\(10\)](#page-2-5) of the main text. The remaining components of \hat{K} are given by

$$
\mathbf{Q} = \frac{\Delta_z}{v} \frac{i D \mathbf{q}}{i \omega - Dq^2} \left(1 + i \omega \tau_{\rm tr} \frac{(\varepsilon^2 + 7 \Delta_z^2)}{\varepsilon^2 + \Delta_z^2} \right), \tag{s19a}
$$

$$
\sigma_{zz} = \frac{\Delta_z^2}{\varepsilon} \frac{1}{i\omega - Dq^2 + \omega^2 \tau_{\text{tr}} \frac{(\varepsilon^2 - 5\Delta_z^2)}{\varepsilon^2 - \Delta_z^2}} \left(1 - i\omega \tau_{\text{tr}} \frac{(\varepsilon^2 - 5\Delta_z^2)}{\varepsilon^2 - \Delta_z^2} \right),\tag{s19b}
$$

where the ω^2 -term was included in the denominator of σ_{zz} because of its importance when taking the limit $q \to 0$. The leading contributions to Eq. [\(s19a](#page-8-0)) in the limit $\omega \tau_{tr} \ll 1$ together with Eq. [\(s19b](#page-8-0)) in the limit $q \to 0$ corresponds to Eqs. $(8,10,16)$ $(8,10,16)$ $(8,10,16)$ of the main text.

It is convenient to rotate the coordinate system such that the new \hat{x} axis lies along q. Let us introduce a rotation matrix U and transform K

$$
U = \begin{pmatrix} q_x/q & -q_y/q & 0 \\ q_y/q & q_x/q & 0 \\ 0 & 0 & 1 \end{pmatrix}, \qquad \tilde{K} = U^{\mathsf{T}} K U, \qquad (s20)
$$

so that the new components of Eqs. [\(s18\)](#page-8-1) become

$$
\tilde{\sigma}_{xx} = \sigma_0 - \frac{Dq^2}{i\omega - Dq^2} i\omega \tau_{\text{tr}} \frac{7\varepsilon^2 + 11\Delta_z^2}{2\pi\alpha(\varepsilon^2 + \Delta_z^2)}
$$
(s21a)

$$
\tilde{\sigma}_{yy} = \sigma_0 + \frac{Dq^2}{i\omega - Dq^2} \left(\sigma_0 - i\omega \tau_{\rm tr} \frac{\varepsilon^2 + 5\Delta_z^2}{2\pi \alpha (\varepsilon^2 + \Delta_z^2)} \right)
$$
(s21b)

$$
\tilde{\sigma}_{yx} = -\tilde{\sigma}_{xy} = \sigma_H, \tag{821c}
$$

and the \tilde{K} tensor can be conveniently be written as

$$
\tilde{K} = \begin{pmatrix}\n\tilde{\sigma}_{xx} & \sigma_{\text{H}} & 0 \\
-\sigma_{\text{H}} & \tilde{\sigma}_{yy} & Q \\
0 & Q & \sigma_{zz}\n\end{pmatrix}
$$
\n(s22)

The components of \hat{K} correspond to different responses at different limits. When discussing the response to an electric field $E_{q\omega}$ we are interested in the limit $\omega \to 0$, but finite q, whereas the response to time-derivative of magnetization m_ω corresponds to finite ω but $q \to 0$. Therefore we write $\tilde{K} = \tilde{K}^{\text{SOT}} + \tilde{K}^{\text{GD}}$, where

$$
\tilde{K}^{\text{SOT}} = \begin{pmatrix} \sigma_0 & \sigma_{\text{H}} & 0 \\ -\sigma_{\text{H}} & 0 & 0 \\ 0 & -Q & 0 \end{pmatrix}, \qquad \tilde{K}^{\text{GD}} = \begin{pmatrix} \sigma_0 & \sigma_{\text{H}} & 0 \\ -\sigma_{\text{H}} & \sigma_0 & 0 \\ 0 & 0 & \sigma_{zz} \end{pmatrix}, \qquad (s23)
$$

which correspond to Eqs. [\(9\)](#page-2-2) of the main text.